

HD64540

LAPB Controller

Description

The HD64540 one-chip CMOS communications device supports the LAPB protocols described by CCITT recommendation X.25. Because of its asynchronous bus interface, the HD64540 can be used with 16-bit external microprocessors.

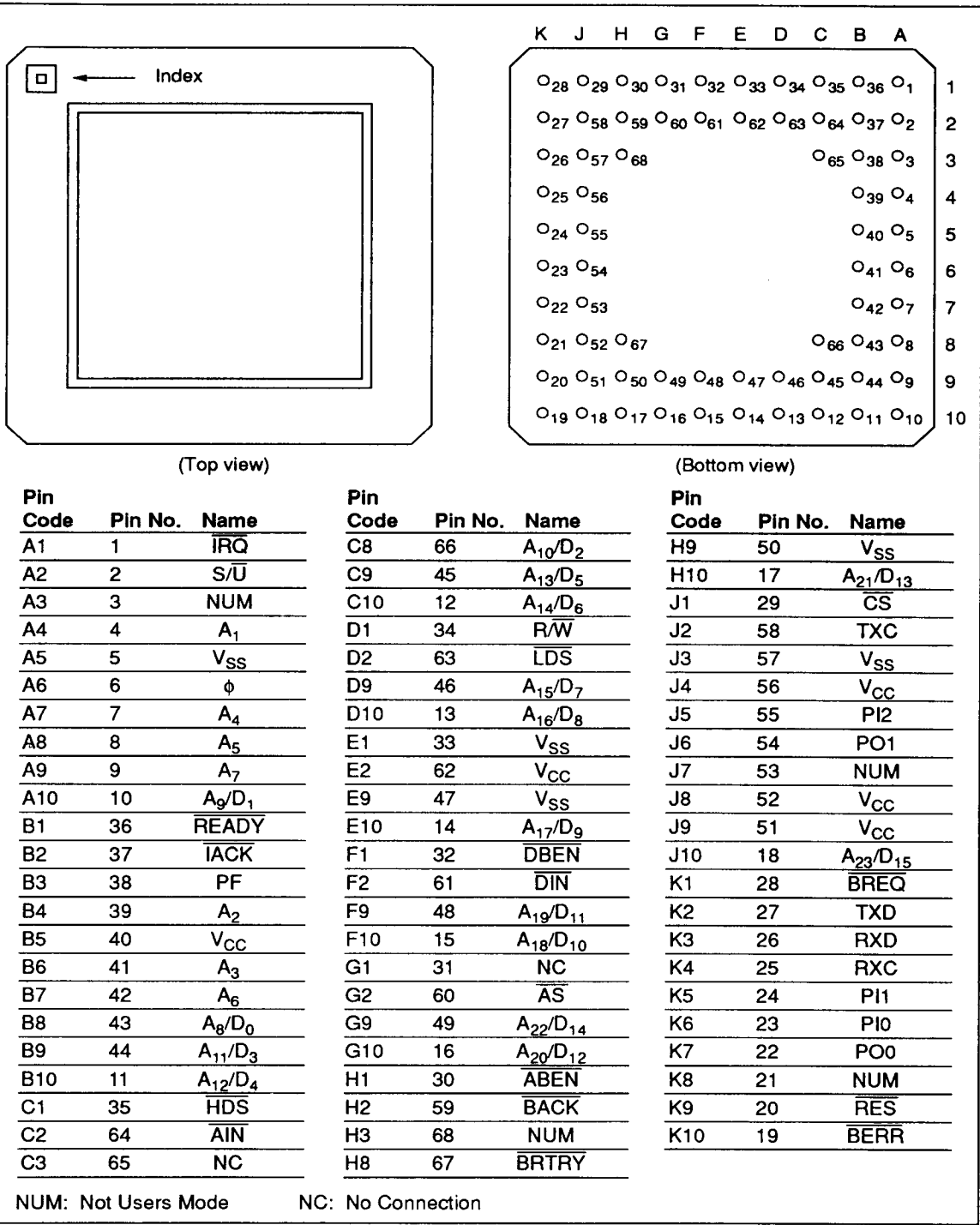
Features

- CCITT recommendation X.25 procedure support
 - Processes X.25 layer 2 protocols (LAPB single link)
 - Reduces main processor load, improving system throughput
- Protocol processing operations
 - HDLC framing, zero insertion/deletion, flag control, retransmission control, and state transition control
- Statistical counters
 - Includes seventeen counters for statistical information: counters for specific frame types transmitted or received, transmission errors, etc.
 - Reports counter status to host processor
- Selectable mode and parameters
 - Terminal (DTE)/network (DCE) mode/transparent mode
 - System parameters programmable
- Chained transmit/receive function
 - Long frames may be stored in multiple data buffers that are chained together and, except for UI, TEST, and XID frames, may be transmitted or received.
 - Transmitted UI, TEST, and XID frame lengths are limited to a single buffer
- High throughput through unique architecture
 - High performance protocol processing and data transmission

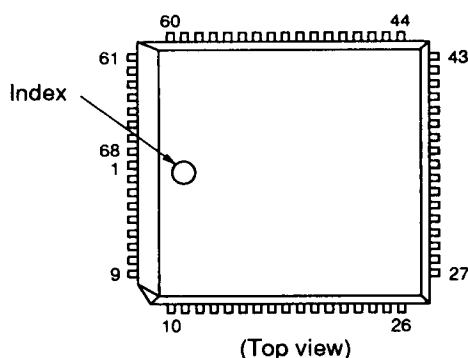
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Pin Arrangement (ceramic pin grid array)

PGA-68 pin



Pin Arrangement (plastic PLCC)



Pin No.	Names	Pin No.	Names	Pin No.	Names
1	V _{SS}	24	A8/D0	47	NUM
2	V _{CC}	25	A9/D1	48	NUM
3	R/W	26	A10/D2	49	PO0
4	HDS	27	A11/D3	50	PO1
5	LDS	28	A12/D4	51	PI0
6	READY	29	A13/D5	52	PI1
7	AIN	30	A14/D6	53	PI2
8	IRQ	31	A15/D7	54	RXC
9	IACK	32	A16/D8	55	RXD
10	NC	33	V _{SS}	56	V _{SS}
11	S/U	34	A17/D9	57	V _{CC}
12	PF	35	A18/D10	58	TXD
13	NUM	36	A19/D11	59	TXC
14	A1	37	A20/D12	60	NUM
15	A2	38	A21/D13	61	BREQ
16	V _{SS}	39	A22/D14	62	BACK
17	V _{CC}	40	A23/D15	63	CS
18	φ	41	V _{SS}	64	AS
19	A3	42	V _{CC}	65	ABEN
20	A4	43	V _{CC}	66	NC
21	A5	44	BRTRY	67	DIN
22	A6	45	BERR	68	DBEN
23	A7	46	RES		

NUM: Not Users Mode

NC: No Connection

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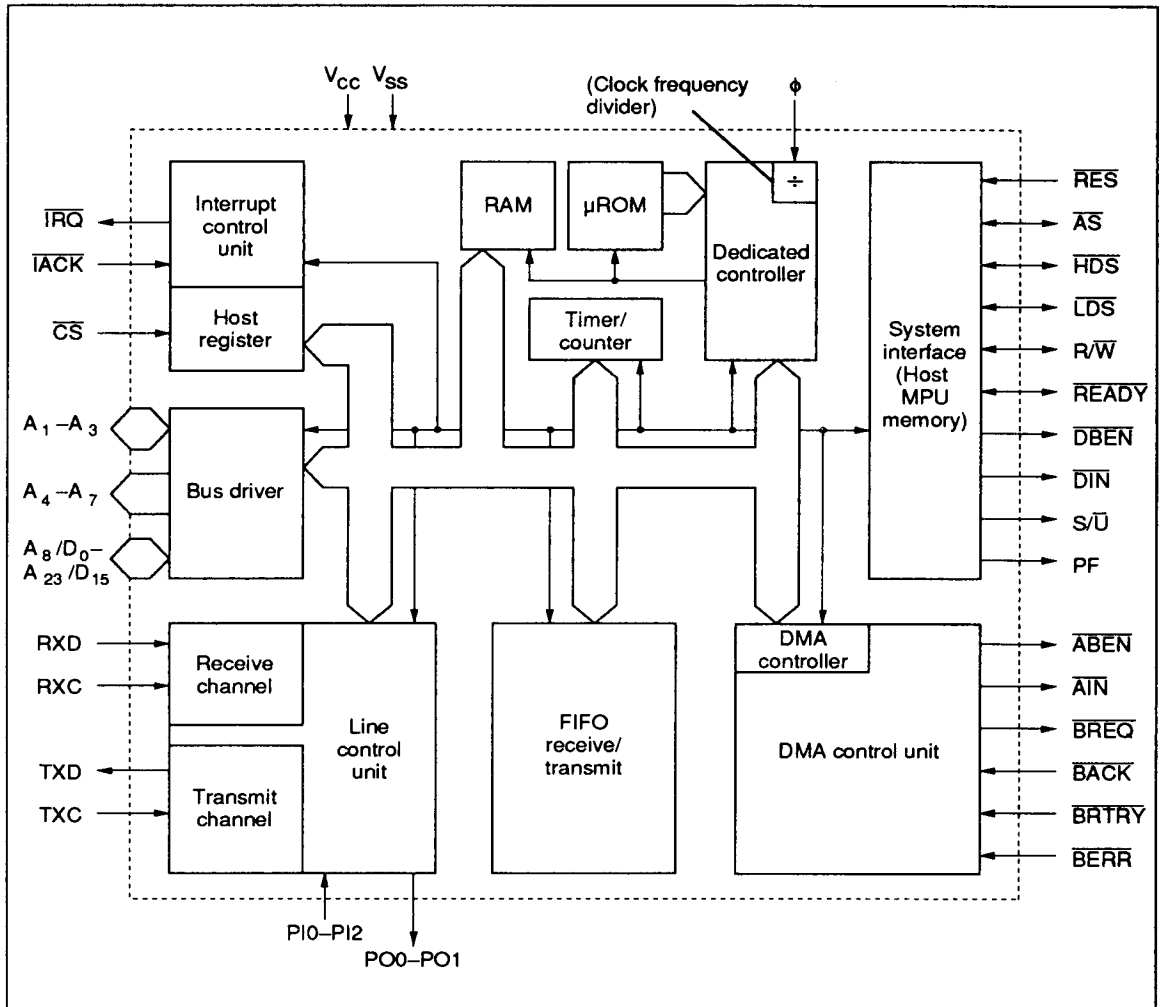
Function Summary

Table 2 summarizes HD64540 functions.

Table 2 HD64540 Function Summary

Feature	Function
Communication protocol	CCITT X.25 layer 2 (LAPB)
Line rate (data rate)	Max 5 Mbps (HD64540R) Max 64 kbps (HD64540)
Number of lines	One full duplex line
Operation mode	Terminal (DTE) mode/network (DCE) mode/transparent mode
Selectable parameters	Maximum number of retransmissions: N2
	Maximum number of octets in an information field: N1
	Maximum time allowed without receiving acknowledgement to transmitted frames (0.1 to 25.5 seconds, 0.1 second steps): T1
	Maximum time allowed for idle state (0.1 to 25.5 seconds, 0.1 second steps or 1 to 255 seconds, 1 second steps): T3
	Maximum number of outstanding I frames (1 to 127): K
	Time for delayed acknowledgement: T2
Diagnostics	Auto-echo
	Local loopback
	Auto-echo and local loopback
Peripheral I/O ports	3 inputs, 2 outputs (general-purpose I/O, level detection)
Data encoding	NRZ serial data
Data transfer with memory	DMA
Address space	16 Mbyte
Data bus width	16 bits (multiplexed with address bus)
Power supply	Single +5 V
Power consumption	130 mW (typ)
Process	CMOS 1.3- μ m
Package	68-pin ceramic PGA (pin grid array), 68-pin plastic PLCC
Ordering code	HD64540B03CP, HD64540B03Y, HD64540RB04Y

Block Diagram



System Configuration

Figure 19 is an example of a system configuration using the HD64540. The HD64540 processes the signal received from the line according to protocol procedure. The processed result is sent to the host MPU. Transmit data is transferred to the line according to commands from the host MPU.

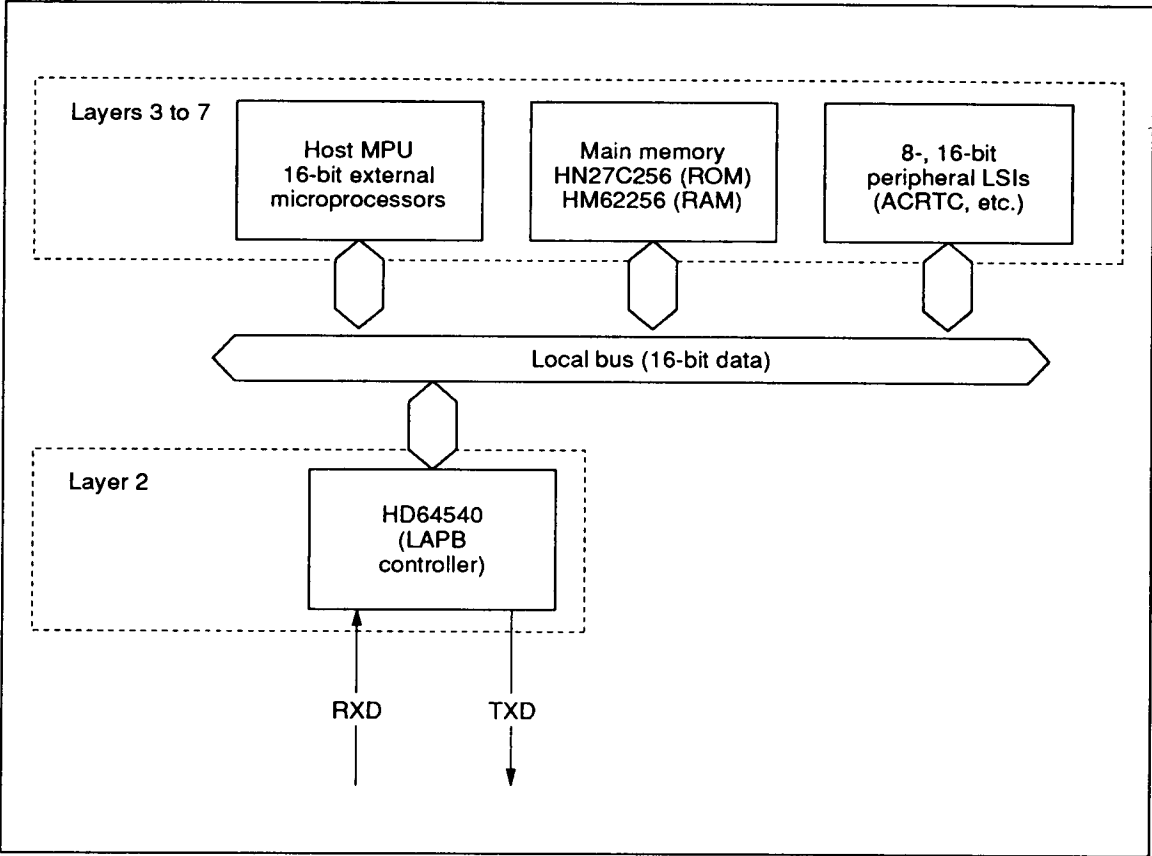


Figure 19 System Configuration Block Diagram

Absolute Maximum Ratings

Table 14 Absolute Maximum Ratings

Parameter	Symbol	Value	Unit
Power supply voltage	V_{CC}^{*2}	7.0	V
Input voltage	V_{in}^{*2}	$V_{SS} - 0.3$ to $V_{CC} + 0.3$	V
Operating temperature	T_{opr}	0 to 70	°C
Storage temperature	T_{stg}	-55 to +150	°C

Notes: 1. Permanent LSI damage may occur if maximum ratings are exceeded. Normal operation should be under recommended operating conditions. If these conditions are exceeded, it could affect the reliability of the LSI.
 2. With respect to V_{SS} (system ground).

Recommended Operating Conditions

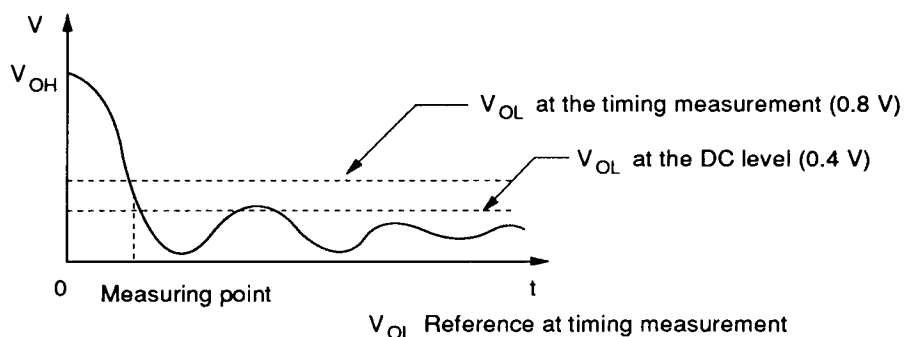
Table 15 Recommended Operating Conditions

Parameter	Symbol	Min	Typ	Max	Unit
Power supply voltage	V_{CC}^{Note}	4.75	5.0	5.25	V
Input low level voltage	V_{IL}^{Note}	-0.3		0.8	V
Input high level voltage	V_{IH}^{Note}	2.0		V_{CC}	V
Operating temperature	T_{opr}	0	25	70	°C

Note: With respect to V_{SS} (system ground).

Timing measurement: The timing measurement point for the output low level is defined at 0.8 V throughout this specification.

The output low level at stable condition (DC characteristics) is defined at 0.4 V.



Electrical Characteristics**DC Electrical Characteristics****Table 16 DC Electrical Characteristics ($V_{CC} = 5\text{ V} \pm 5\%$, $V_{SS} = 0\text{ V}$, $T_a = 0^\circ\text{C}$ to $+70^\circ\text{C}$, unless otherwise noted)**

Parameter	Symbol		Min	TypNote	Max	Unit	Condition
Input high level voltage	V_{IH}	ϕ (clock)	2.4	—	V_{CC}	V	
		Others	2.0	—	V_{CC}	V	
Input low level voltage	V_{IL}		−0.3	—	0.8	V	
Input leakage current	I_{IN}		—	—	2.5	μA	
Output high level voltage	V_{OH}		2.4	—	—	V	$I_{OH} = -200\text{ }\mu\text{A}$
Output low level voltage	V_{OL}		—	—	0.4	V	$I_{OL} = 1.6\text{ mA}$
Output leakage current	I_{LOH}		—	—	10	μA	
Pin capacitance	C_P		—	—	15	pF	$V_{in} = 0\text{ V}$ $F = 1\text{ MHz}$ $T_a = 25^\circ\text{C}$
Current consumption	I_{CC}		—	26	50	mA	

Note: $T_a = 25^\circ\text{C}$, $V_{CC} = 5.0\text{ V}$.